Seat No.				Set	Ρ	
M.Sc. (Semester - I) (New) (NEP CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Mathematical Physics (2322101)						
	Day & Date: Friday, 05-01-2024 Max. Marks: 60 Time: 03:00 PM To 05:30 PM Max. Marks: 60					
Instru	Instructions: 1) All questions are compulsory. 2) Figures to the right indicate full marks.					
Q.1	A)	1) 2)	The value of $\int_{-\pi}^{\pi} \cos(mx) \sin(nx) dx =$ a) 1 b) $a-1$ c) 0 d) π If $ z^2 - 1 = z^2 + 1$ then z lies on a) the real axis b) the imaginary axis c) a circle d) on ellipse A point at which a function $f(z)$ is not analytic is known as or singularity of the function. a) Scalar point b) Singular point c) Non-singular d) None of these Find the pole of $f(z) = \sin \frac{1}{(z-a)} =$	s a	08	
		5)	a) $z = a$ b) $z = 0$ c) $z = 1$ d) $z = 4$			
		6)	Legendre polynomial is a set of function.a) orthogonal b) oddc) even d) real			
		7)	If $f(z) = e^{2z}$ then the imaginary part of $f(z)$ is a) $e^{y} \sin x$ b) $e^{x} \cos y$ c) $e^{2x} \cos 2y$ d) $e^{2x} \sin 2y$			
		8)	What are the eigen values of $\begin{pmatrix} 1 & -i \\ i & 1 \end{pmatrix}$?a) Both are 0b) 0 and 1c) 0 and -1 d) 0 and 2			
I	c) 0 and -1 d) 0 and 2				04	

Page 2 of 2

Q.2 Answer the following. (Any Six)

- Find the pole $f(z) = \sin\left(\frac{1}{z-z}\right)$ a)
- What are the conditions for a matrix to be orthogonal matrix? b)
- Solve $\frac{d^2y}{dx^2} 6\frac{dy}{dx} = 9y = 0$ C)
- Find the Laplace transform of the function d)

$$f(t) = te^{-t}\sin 2t$$

Find the pole of $f(z) = \frac{\sin(z-a)}{(z-a)^4}$ e)

Show that inverse of an orthogonal matrix is orthogonal. f)

g) Solve
$$\frac{d^2y}{dx^2} - 5\frac{dy}{dx} + 6y = 0$$

Define singular point, explain in details its types with example. h)

Q.3 Answer the following. (Any Three)

- Discuss in details Cauchy's Integral Formula. a)
- State and prove the Parseval's Theorem. b)
- Show that the eigen value of Hermitian matrix are real. C)
- Find the Fourier Transform of e^{-ax^2} where a > 0d)

Q.4 Answer the following. (Any Two)

Write matrix A gives below as the sum of symmetric & a skew symmetric a) matrix.

$$A = \begin{pmatrix} 1 & 2 & 4 \\ -2 & 5 & 3 \\ -1 & 6 & 3 \end{pmatrix}$$

- b) In square wave expand the function $f(x) = 0; -\pi \le x \le 0$ $f(x) = h; 0 \le x \le \pi$ fourier
- Evaluate the following integral using residue Theorem. C) $\int_{C} \frac{1+z}{z(2-z)} dz$ where c is circle |z| = 1

Q.5 Answer the following. (Any Two) a) Evaluate $\int_0^\infty \frac{\cos 3\theta}{5+4\cos \theta} d\theta$

- **b)** Solve; $x \frac{dy}{dx} + y \log y = xy e^x$
- Solve the differential equation. C)

 $y \log y \, dx + (x - \log y) dy = 0$

12

12

SLR-FA-1

12

lo.		Set P
M.:	Sc. (Se	emester - I) (New) (NEP CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Solid State Physics (2322102)
		Inday, 07-01-2024 Max. Marks: 60 I To 05:30 PM
struc) All questions are compulsory. ?) The figure to right indicate full marks.
).1 A) Cho 1)	Oose the correct alternative.08Conductivity of metals depends upona) The nature of the materialb) Number of free electronsc) Resistance of the metald) Number of electrons
	2)	At what temperature does ferromagnetic material become paramagnetic? a) Melting b) Curie c) Neel d) None of these
	3)	Which of the following is a strong magnet? a) Diamagnetic material b) Paramagnetic material c) Antiferromagnetic material d) Ferromagnetic material
	4)	 Electronic polarization also known as a) molecular polarization b) magnetic polarization c) atomic polarization d) orientation polarization
	5)	What is the phenomenon where a material exhibits zero electrical resistance below a certain critical temperature? a) Superconductivity b) Conductivity c) Resistance d) Insulation
	6)	 For which of the following is magnetic susceptibility negative? a) Paramagnetic Materials only b) Ferromagnetic Materials only c) Diamagnetic Materials d) none of the above
	7)	 The sprinkling of water reduces slightly the temperature of a closed room because a) Water is a bad conductor of heat b) Water has a large lantern heat of vaporization c) The temperature of the water is less than the room d) None of the above

- Which of the following is a property of a superconductor?
 a) Perfect diamagnetism
 b) High electrical conductivity
 d) Non-zero resist 8)
- High electrical resistance Non-zero resistivity

SLR-FA-2 Set P

Seat Nc

Da Tin

Q.

	B)	 Fill in the blanks OR write true / false. 1) The SI unit of magnetic field intensity is 2) The magnetization 'M' of a superconductor in a field is 3) When a paramagnetic material is heated above Curie temperature it becomes non-magnetic. 4) The temperature above which an antiferromagnetic material becomes paramagnetic is called the melting temperature. 	04
Q.2	Ans a) b) c) d) e) f) g) h)	wer the following. (Any Six). What is Curie Temperature? Define diamagnetic materials. Define specific heat. What is orientational polarization? What is an extrinsic semiconductor? What is penetration depth? State the concept of ferroelectricity. Define Neel temperature.	12
Q.3	Ans a) b) c) d)	wer the following (Any Three) Explain in Brillouin zones in 2-D. Write about the direct and indirect band gap of semiconductors. Explain Meissner's effect. Write a note on the conductivity of solids.	12
Q.4	Ans a) b) c)	wer the following (Any Two) Electronic polarization Explain the Kronig-Penny model. Explain the thermodynamics of superconductors.	12
Q.5	a)	wer the following (Any Two) Write the difference between metal, semiconductors and insulators. Write a note on Josenhson's tunnelling and its theory.	12

b) Write a note on Josephson's tunnelling and its theory.c) Explain the Clausius-Mossotti equation

Seat	t						
No.						Set	Ρ
	M.S		ter - I) (New) (NEP C PHYSICS (ENEF Analog and Digital El	RGY	STUDIES)	lov-2023	
		te: Tuesday, 00 PM To 05			I	Max. Marks	: 60
Instr	uctio		uestions are compulsory. e to right indicate full mar	ks.			
Q.1	A)	1) The fe a) A b) A c) A	eedback path in an op-am resistor capacitor resistor and capacitor in resistor and capacitor in	p integ series			08
		a) M b) C c) M	lexer has /any input and one outpu One input many output /any input and many out One input and one output				
		a) C	mp is a type of am Current Power	plifier. b) d)	Voltage Resistance		
		a) P	p-amp comparator circuit Positive feedback Regenerative feedback	b)	Negative feedback		
		a) V	he output of inverting amp /o = AV _{in} /o = -A(V _{in1} -V _{in2})	b)	V _o = -AV _{in} None of the mentioned		
		a) C b) C c) C	happen if any positive inp Dutput reaches saturation Dutput voltage swing's pea Dutput will be a sine wave Dutput will be a non-sinus	level ak to p form	eak	p configura	tion?
		7) In 808 a) T c) F		nany in b) d)			
		8) In how a) 2 c) 4		univer b) d)	sal shift register operate 3 5	S	
	B)	1) The da 2) 3)	blanks OR Write True /Fata in stack is called Circuit is used as signal bit program counter is av oltage gain of a voltage b	 source vailable	e in 8085.		04

	 b) Draw AND gate with truth table. c) What is the function of IO/M signal in the 8085? d) What is differential amplifier. e) What is dynamic shift register. f) Why op-amp called direct coupled high differential circuit. g) What is microprocessor? Give the power supply & clock frequency of 8085. h) Define CMRR frequency response. 	
Q.3	 Answer the following. (Any Three) a) Explain the timing diagram of 8085. b) Explain Multiplexers and Demultiplexers. c) Write a note on RS flip flop and JK flip flop. d) Explain Inverting and Non inverting amplifier. 	12
Q.4	 Answer the following. (Any Two) a) Define Oscillators? Explain their types. b) Write a note on 8085 instruction set. c) Explain in details of instrumentation amplifier. 	12
Q.5	 Answer the following. (Any Two) a) Discuss Synchronous and Asynchronous counter. b) Draw and explain 8:1 Multiplexers. c) What is multivibrator? Explain the difference between the three types of multivibrators. 	12

Q.2 Answer the following. (Any Six)a) Define Input offset voltage.

Seat No.

M.Sc. (Semester - I) (New) (NEP CBCS) Examination: Oct/Nov-2023 **PHYSICS (ENERGY STUDIES) Research Methodology in Physics (2322105)**

Day & Date: Thursday, 11-01-2024 Time: 03:00 PM To 05:30 PM

Instructions: 1) All questions are compulsory.

2) Figure to right indicate full marks.

Q.1 A) Choose the correct alternatives from the options.

- 1) A researcher is generally expected to
 - a) Study of existing literature in afield
 - b) Generate new principle and theories
 - c) Synthesis the ideas given by others
 - d) Evaluate the finding of a study

2) Oxides and Nitrides can be applied by _____ evaporation.

- a) E-beam b) Thermal
- c) Magnetron d) DC

Tuning of the refractive index with the density of the films is possible 3) by sputtering.

- a) Magnetron b) DC
- d) RF c) lon beam

The main problem in questionnaire is . 4)

- a) Accessible to Diverse Respondent
- b) Greater Anonymity
- c) Shows an inability of respondent to provide information
- d) None of these
- 5) UV-Vis spectroscopy cannot analyze compounds that with light.
 - a) don't interact b) interact c) merge
 - d) none of the above
- Technique that allow several members of a hiring company to 6) interview a job candidate at the same time is a) Panel Interview
 - b) Self-administered interview
 - c) Mail Interview d) Electronic Interview
 - The most common scales used in research are .
 - a) Nominal b) Ratio
 - c) Ordinal
- 8) By selecting laser operating conditions, control over microstructure is
 - a) possible c) not defined

7)

b) impossible

d) All of the above

d) both a) and b)

SLR-FA-5

Set

Max. Marks: 60

04

		1)	In E-beam evaporation, only the target is heated and not the crucible. (True/False)	
		2)	In thermal evaporation, films in the thickness range of angstroms to microns are obtained. (True/False)	
		3)	Applied research is conducted to solve practical problems. (True/False)	
		4)	The basic research is also called as fundamental research. (True/False)	
Q.2	An		the following. (Any Six)	12
	a)		te the various sampling methods.	
	b)		te the applications of Pulsed Laser Deposition.	
	C)		at are the applications of UV-Vis Spectroscopy?	
	d)		at are patents?	
	e) f)		ine Quantitative research method. ine physical and chemical vapour deposition.	
	f) g)		te primary literature review sources.	
	9) h)		at are the applications of FTIR Spectroscopy.	
Q.3	Ans	swer	the following. (Any three)	12
	a)		te a note on Descriptive Vs Analytical research methods.	
	b)		erentiate between SEM and TEM techniques.	
	C)		te a note on web as source.	
	d)	Writ	te the basic mechanism of sputtering technique.	
Q.4			the following. (Any two)	12
	a)		ine Research? What are characteristics of Research.	
	b)		cuss different type of Research.	
	C)	vvri	te a note on Review of Literature.	
Q.5			the following. (Any two)	12
	a)		at is Research Design? What are its essentials	
	b)		te in detail about the concept of Chemical Bath Deposition.	
	c)	Evn	lain in detail about Spray Pyrolysis	

c) Explain in detail about Spray Pyrolysis.

B) Fill in the blanks OR Write True or False:

Seat No.					Set	Ρ			
M.Sc. (Semester - I) (Old) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Mathematical Physics (MSC40101)									
	te: Friday, 0 00 AM To 0				Max. Marks	: 80			
Instructio	, ,	uestions are compuls res to the right indicat	•	ks.					
Q.1 A)	1) The p a) a	prrect alternative. roduct of a singular m unit matrix n orthogonal matrix	b)	its adjoint is a null matrix Square matrix		10			
			he Fourier b) d)		erval				
	a) s c) o	nd B are orthogonal m ymmetric rthogonal	b) d)	antisymmetric unitary					
	4) Evalu a) 2 c) ^π		$\frac{\sin^2\theta}{5+4\cos\theta}$ b) d)	π					
	5) The v a) 1 c) 0	alue of $\int_{-\pi}^{\pi} \cos(mx) dx$	sin(<i>nx</i>) dx b) d)						
	a) tł	$-1 = z^2 + 1$ then z ne real axis circle	lies on b) d)	the imaginary axis on ellipse					
	 7) Find t a) z c) z 		b)	z = 0 z = 4					
	a) 2	uchy's Residues theorem $\pi i \sum_{j=1}^{n} a_{-1} z_j$ $\pi i \sum_{j=1}^{n} a_{+1} z_j$	b)						

9) _____ is the real part (Re Z) & _____ is the imaginary (Im Z), of the given z = (1 + i)/(2 - 3i).

a)	$-\frac{1}{13} \& \frac{5}{13}$	<i>)</i> / (,	b)	$-\frac{1}{11}$ & $\frac{4}{13}$
c)	$\frac{1}{3}$ & $-\frac{5}{13}$			d)	$\frac{1}{09}$ & $\frac{5}{13}$

10) Legendre polynomial is a set of _____ function.a) orthogonalb) odd

c) even d) real

B) Fill in the blanks OR write true/false.

- a) A necessary and sufficient condition that solution y_1 and y_2 of y'' + p(x)y' + q(x)y = 0 is linearly independent is that the Wronskian is zero. (True/False)
- b) Fourier series can be used to represent discontinuous where all orders of derivatives need not exist. (True/False)
- c) The Fourier transform operator is unitary.
- d) The first order ODE can never be linear separable and exact at the same time. (True/False)
- e) A Fourier transform is a linear operator. (True/False)
- f) A square matrix is called orthogonal if $A = A^{-1}$. (True/False)

Q.2 Answer the following.

- a) If A and B are two orthogonal matrices, show that AB is also orthogonal matrix.
- **b)** Find the Laplace transform of $\frac{s^2 a^2}{(s^2 + a^2)^2}$

c) Find the residue of
$$\frac{1}{(z^2+1)^3}$$
 at $z = i$
d) Solve $y e^y dx = (y^3 + 2xe^y)dy$

Q.3 Answer the following.

a) Solve $x \frac{dy}{dx} + y \log y = xye^x$ b) Find the eigen value of a matrix $\begin{bmatrix} 2 & 1 & 1 \\ 1 & 2 & 1 \\ 0 & 0 & 1 \end{bmatrix}$ 08

Q.4 Answer the following.

a)

Determine the value of α, β, r when $\begin{bmatrix} 0 & 2\beta & r \\ \alpha & \beta & -r \\ \alpha & -\beta & r \end{bmatrix}$ is orthogonal.

b) Determine the poles of the function z, $f(z) = \frac{1}{z^4 + 1}$ **08**

16

Q.5 Answer the following.

Q.5	a)	Solve $\sin x \frac{dy}{dx} + 2y = \tan^3 \left(\frac{x}{2}\right)$ Verify Cayley - Hamilton Theorem for the following matrix. $A = \begin{bmatrix} 2 & -1 & 1 \\ -1 & 2 & -1 \\ 1 & -1 & 2 \end{bmatrix}$ and use the theorem to find A^{-1}	08 08
Q.6	Ans a) b)	swer the following. Find the order of each pole and residue of $\frac{1-2z}{z(z-1)(z-2)}$ Show that the eigen value of Hermitian matrix are real.	08 08
Q.7	An: a)	swer the following. In square wave expand the function. $f(x) = 0; -\pi \le x \le 0$ $f(x) = 4; -0 \le x \le \pi$ Fourier.	08
	b)	Explain Laplace transform of Derivatives.	08

Seat No.		Set P					
M.Sc. (Semester - I) (Old) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Solid State Physics (MSC40102)							
	Sunday, 07-01-2024 PM To 06:00 PM	Max. Marks: 80					
Instructions:	 A. Nos. 1 and. 2 are compulsory. Attempt any three questions from Q Figure to right indicate full marks. 	. No. 3 to Q. No. 7					
Q.1 A) CI 1)	hoose the correct alternative. Effective mass is equal to n a) Mean c) Residual	10 nass for free electron. b) real d) zero					
2)	Elemental solid dielectric has only _ a) Electronic c) orientational	polarization. b) ionic d) all					
3)	 In the case of p-type semiconductor a) Below near to conductor band b) Above near to valence band c) Below near to valence band d) At the middle of the valence and 	d					
4)	In the case of superconductor, at To a) Zero c) Infinite	c conductance becomes b) Finite d) None of the above					
5)	has a positive temperature c a) Metal c) Insulator	oefficient of resistance. b) Semiconductor d) Dielectric					
6)	The coordination number of HCP is a) Two c) Six	 b) Four d) Twelve					
7)	Plane cut to negative x-axis have th a) (011) c) (110)	e miller indices b) (001) d) (-100)					
8)	The zone lies in between +π/2 to – a) 1 st c) 3rd	$\pi/2$ is the Brillion zone. b) 2^{nd} d) 0^{th}					
9)	Relative permittivity (ε_r) of the air is a) 2 c) 1	s b) 0.5 d) 0					
10	 Intrinsic concentration of charge car 	rriers in a semiconductor varies as b) T ² d) 1/T					

	B)	 Fill in the blanks OR Write True or False Some conductors are below critical temperature. FCC structure contains the contribution of atoms. The packing fraction of the BCC structure is 74%. (T/F) NaCl shows orientation polarization. (T/F) Diamond is a conductor. (T/F) The addition of pentavalent impurity creates an n-type semiconductor. (T/F) 	06
Q.2	a) b) c)	wer the following (any four) Write about orientational polarization. Explain Meissner's effect. Derive the rectifier equation Show that in the case of an intrinsic semiconductor $E_f = (E_c + E_v)/2$ Write a note on dielectric Breakdown.	16
Q.3		wer the following	
	a)	What is meant by imperfections in crystals? Explain the various defects in the crystal.	10
	b)		06
Q.4	Ans [.] a) b)		10 06
Q.5	Ans	wer the following	
	a) b)		80 08
Q.6	Ans a) b)	I	10 06
Q.7	Ans [.] a) b)		10 06

Seat No.				S	Set	Ρ		
NO.	N	I.Sc.	(Semester - I) (Old) (CBCS) Examination: Oct/No PHYSICS (ENERGY STUDIES)	v-2023)			
	Analog and Digital Electronics (MSC40103)							
			esday, 09-01-2024 I To 06:00 PM	Max. N	1arks	: 80		
Instru	ctio	2) All questions are compulsory.) Attempt any three questions from Q.3 to Q.7.) Figure to right indicate full marks.					
Q.1	A)	Cho 1)	ose correct alternative. (MCQ) The basic SR flip-flop can be constructed by cross coupling which of the gates? a) AND or OR gate b) XOR or XNOR gate	by usin	g	10		
			c) NOR or NAND gate d) AND or NOR gate					
		2)	In JK flip-flop "no change" condition appear when a) $J = 1, K = 1$ b) $J = 0, K = 0$					
			a) $J = 1, K = 1$ b) $J = 0, K = 0$ c) $J = 1, K = 0$ d) $J = 0, K = 1$					
		3)	Which is the 16-bit register for 8085 microprocessor? a) Stack pointer b) Accumulator c) Register B d) Register C					
		4)	 The feedback path in an op-amp integrator consists of a) A resistor b) A capacitor c) A resistor and capacitor in series d) A resistor and capacitor in parallel 					
		5)	 Multiplexer has a) Many input and one output b) One input many output c) Many input and many out put d) One input and one output 					
		6)	 The op-amp comparator circuit uses a) Positive feedback b) Negative feedback c) Regenerative feedback d) No feedback 					
		7)	Op- amp is a type of amplifier a) Current b) Voltage c) Power d) Resistance					
		8)	 An XOR gate can be used for a) Inverter and non-inverter b) Only inverter c) Only non-inverter d) None of the above 					

06

16

9)	Which of the following addressing method does the instruction,
	MOV AX,[BX] represent?

- a) register indirect addressing mode
- b) direct addressing mode
- c) register addressing mode
- d) register relative addressing mode
- 10) Which of the following is a property of RST 7.5 interrupt?
 - a) It is a non-maskable interrupt
 - b) It has 3rd highest priority
 - c) It uses level-triggered signal
 - d) Its vectored address is 003C H

B) Fill in the blanks

- 1) In an instrumentation amplifier, the output voltage is based on the _____ times a scale factor.
- 2) The output voltage of a voltage buffer is _____ with the input voltage.
- 3) The voltage gain of a voltage buffer is _____.
- 4) The data in stack is called
- 5) The sequential circuit is also called _____
- 6) There are _____ general purpose registers in 8085 microprocessor.

Q.2 Answer the following

- a) Define
 - i) Input offset voltage
 - ii) Voltage follower
- b) Draw AND gate and NOT gate with truth table.
- c) What is microprocessor? Give the power supply & clock frequency of 8085 and List the allowed register pairs of 8085.
- d) Write a note on Demorgan's Theorem.

Q.3 Answer the following.

	a) b)	Draw and explain architecture of 8085 microprocessor. Explain Multiplexers and Demultiplexers.	10 06
Q.4	Ans	swer the following.	
	a)	What is multivibrator? Explain the difference between the three types of multivibrators.	10
	b)	Draw and explain 8:1 Multiplexers.	06
Q.5	Ans a) b)	wer the following. Explain the operation of three op-amp instrumentation amplifier. Define Oscillators? Explain their types.	10 06
Q.6	Ans	swer the following.	
	a)	Explain inverting configuration of Op amp as a summing, scaling and averaging Amplifier.	10
	b)	Explain Inverting and Non inverting amplifier.	06
Q.7	Ans	swer the following.	
	a)	Explain the instruction set of 8085 microprocessor.	10
	b)	Draw and explain memory read cycle of 8085 microprocessor.	06

Seat No.			Set	Ρ
	M.Sc.	(Semester - I) (Old) (CBCS) Examination: Oct/No PHYSICS (ENERGY STUDIES) Classical Mechanics (MSC40108)	ov-2023	
•		ursday, 11-01-2024 I To 06:00 PM	Max. Marks	s: 80
Instru	2) Q. Nos. 1 and. 2 are compulsory. 2) Attempt any three questions from Q. No. 3 to Q. No. 7 3) Figure to right indicate full marks.		
Q.1	,	bose correct alternative. The position of a particle at any time t subjected to resistive. a) $x = k.(1 + e^{-kt})/v_o$ b) $x = kv_o(1 - e^{-kt})$ c) $x = v_o(1 - e^{-kt})/k$ d) $x = kv_o(1 + e^{-kt})$	e force is	10
	2)	The rate of momentum change of an open system is equal a) $T + MU$ b) $F - MV$ c) $W - MV$ d) $F + MU$	to	
	3)	The reduced mass of two bodies into equivalent one body a) $(m_1 + m_2)/(m_1.m_2)$ b) $(m_1.m_2)/(m_1 - m_2)$ c) $m_2/(1 + m_2/m_1)$ d) $m_1/(1 + m_2/m_1)$	is	
	4)	The time derivative of generalized co-ordinate is a) Generalized force b) Generalized velocity c) Generalized momentum d) None of these	,	
	5)	For $E > 0$ and $\varepsilon > 1$, the nature of the orbit is a) Circle b) Parabola c) Ellipse d) Hyperbola		
	6)	The generalized momentum is equal toa) $\partial L/\partial q_j$ b) $\partial L/\partial \dot{p}_j$ c) $\partial L/\partial \dot{q}_j$ d) $\partial L/\partial p_j$		
	7)	Which of the following defines a conservative force <i>F</i> ? a) $dF/dt = 0$ b) $\nabla F = 0$ c) $\nabla \times F = 0$ d) $\oint F. dr = 0$		
	8)	Poisson brackets are under canonical transformati a) Variant b) nullified c) anti-symmetric d) invariant	on.	
	9)	 Generalized coordinated a) are independent of each other b) depend on each other c) are always cartesian coordinates d) are always spherical polar coordinates 		
	10)	The $F_2 = \sum q_k P_k$ transformation defined as a) generates exchange transformation b) generates identity transformation c) is not canonical transformation d) None of the above		

d) None of the above

	B)	 Fill in the blanks or write true /false. 1) Scleronomic constraint do not explicitly depends on time. (True/False) 2) q_j's which are absent in <i>L</i> are cyclic coordinates. (True/False) 3) Rutherford's differentia scattering cross section has dimensions of solid angle. (True/False) 4) The Euler-Lagrangian differential equations is 5) Lagrangian is equal to 6) [L_x, L_y] = 	06
	a) b) c) d)	 swer the following questions. Which conditions are used to verify that the transformation is canonical? Prove any one condition. Prove that forces acting on a particle are conservative then the total energy <i>E</i> of a particle is conserved. Distinguish between the configuration space and phase space. Define Hamiltonian. Give its physical significance. 	16
Q.3	An a) b)	 swer the following. Derive the equation of motion of a particle and deduce the acceleration of Atwood machine under constant force. Obtain the equation of motion of 1) a particle subjected to a resistive force 2) a projectile (no resistance) 	10 06
Q.4	An a) b)	swer the following. Derive the formula for Rutherford scattering cross-section. Derive an equivalent equation for reduction to one body problem from two body problem.	10 06
Q.5	a)	swer the following. State the Kepler's laws of planetary motion and prove the Kepler's third law. Deduce the Lagrange's equation of motion from Hamilton's principle and using derive the generalized momentum.	10 06
Q.6	An a) b)	swer the following. Derive canonical equations of Hamilton. Also write the procedure for constructing Hamiltonian. Obtain Hamilton's equation for one dimensional harmonic oscillator.	10 06
Q.7	An a) b)	swer the following. State and prove Poisson's theorem. Prove the Jacobi identity [<i>V</i> , [<i>V</i> , <i>W</i>]] + [<i>V</i> , [<i>W</i> , <i>U</i>]] + [<i>W</i> , [<i>U</i> , <i>V</i>]] = 0	10 06

Page 1 of 2

SLR-FA-11

Seat	
No.	

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Quantum Mechanics (MSC40201)

Day & Date: Monday, 18-12-2023 Time: 11:00 AM To 02:00 PM

Instructions: 1) Q. Nos. 1 and. 2 are compulsory.

2) Attempt any three questions from Q. No. 3 to Q. No. 7

3) Figure to right indicate full marks.

Q.1 A) Fill in the blanks by choosing correct alternative.

- 1) If Ψ_a and Ψ_b are said to be orthogonal to each other, then which of the following is true.
 - a) $\langle \Psi_a | \Psi_b \rangle = 1$ b) $\langle \Psi_a | \Psi_b \rangle = \infty$
 - c) $\langle \Psi_a | \Psi_b \rangle = \sqrt{1/2}$ d) $\langle \Psi_a | \Psi_b \rangle = 0$
- 2) If two operators do not commute with each other, then which of following statement is true.
 - a) They do not share common eigenfunction.
 - b) They do share common eigenfunction.
 - c) Their eigenvalues are same.
 - d) They must anti-commute.

3) The minimum energy of particle confined to one dimensional rigid box is obtained by substituting *n* equal to _____.

- a) one b) zero
- c) half d) two

4) The total energy operator or Hamiltonian operator is given by $H^{\wedge} =$ _____.

a) $\hat{p}^2/2m$ b) V(x) $(\hat{p}^2/2m) + V(x)$ $(\hat{p}^2/2m) - V(x)$ c) d) 5) Energy of harmonic oscillator is, E = $(1/2)\hbar\omega$ nħω a) b) $(n + 1/2)\hbar\omega$ d) $(n - 1/2) \hbar \omega$ C) 6) The eigen value of L^2 is _____. $l(l+1)\hbar^{2}$ b) $l(l-1)\hbar$ a) $l(l^2 + 1)\hbar^2$ $l(l+1)\hbar$ c) d) Which of the following is lowering operator _____. 7) $L_{r} + iL_{v}$ b) $L_x - L_v$ a) $L_x - iL_y$ c) d) 0 8) The commutation relation between $[x, P_x]$ and $(\partial/\partial x, x]$ is a) *i*ħ, 0 b) 0,*i*ħ $-i\hbar$, 1 d) *i*ħ, 1 c) 9) Which of the following equation is correct?

a) $[\hat{y}, \hat{p}z] = i\hbar$ b) $[\hat{x}, \hat{p}y] = i\hbar$

c) $[\hat{z}, \hat{p}x] = i\hbar$ d) $[\hat{z}, \hat{p}z] = i\hbar$

Max. Marks: 80

Set

- 10) Which of the following equations is/are correct?
 - i) $K = r \times p$
 - ii) $L = iL_x + jL_y + kL_z$
 - iii) $L^2 = L.L$
 - iv) $L^2 = L_x^2 + L_y^2 + L_z^2$
 - i and ii only a) c)
- iii and iv only are correct b) i, ii and iv are correct All are correct d)

B) Fill in the blanks or Write True /False.

- Diffraction and interference are the evidence of wave nature of 1) matter. (True/False)
- 2) Eigen values of Hermitian operator are not real. (True/False)
- 3) Inner product of Bra and Ket in Quantum mechanics is always 1. (True/False)
- 4) For a free particle the potential energy V(x) =_____.
- 5) Potential energy of a particle in harmonic oscillator having mass mis
- The linear momentum operator is given by . 6)

Q.2 Answer the following.

- Normalize the following wave- function in one- dimension: a)
 - $\psi(x) = Ae^{-ax}$ for x > 0
 - $= Ae^{+ax}$ for x < 0

where α is a positive constant.

- Prove that eigen function of Hermitian operator with different eigen values b) are orthogonal to each other.
- Explain unitary transformation. C)
- Define the different postulate of Quantum mechanics. d)

Q.3 Answer the following.

- Derive the time independent Schrödinger equation in 3D. a) 10 06
- Deduce the continuity equation. b)

Q.4 Answer the following.

a)	Obtain Schrödinger's wave equation for Hydrogen atom in terms of	10
-	spherical polar coordinates, express its radial and angular parts.	
b)	Define angular momentum and explain the commutation relation.	06

b) Define angular momentum and explain the commutation relation.

Q.5 Answer the following.

- What is momentum eigen function in the co-ordinate representation? a) 10 Elaborate. 06
- Write down the co-ordinate and momentum representation. b)

Q.6 Answer the following.

- What is the Clebich Gordon coefficient? Explain the construction procedure. 10 a) With simple examples.
- Describe the Pauli spin matrices. 06 b)

Q.7 Answer the following.

- Define square well potential in one dimension. Discuss motion of a particle 10 a) of mass m when energy of the particle is less than potential $(E < V_0)$. 06
- Obtain eigen values of operators L^2 and Lz. b)

06

			Electrodynamics (N	ASC	;40202)	
: 11:0	00 AN 0 ns: 1 2	/I To I) Q. 2) At	ay, 19-12-2023 02:00 PM No. 1 and 2 are compulsory. tempt any Three questions fron gures to the right indicate full m			80
A)		ose Div a)	the correct alternatives from ergence of the curl of any vector	the or fie b)	options.	10
	2)	forr a)	ich one of the fundamental equ n the basis of electromagnetic f Faraday law Gauss law of electrostatic	theo b)	•	
	3)	a)	entz electric force has direction Similar to electric field Scalar quantity	b)	Opposite to electric field None	
	4)	a)	e Poynting vector P is equal to _ E . H E/H	b)	 E × H H/E	
	5)	me a)	ich property of an electromagn dium in which it is travelling? Velocity Time period	b)	wave, depends on the Frequency Wave length	
	6)	am a)	the skin definition of skin dept plitude reduces to Nearly one fifth One half	b)	is distance over which field 1/e One fourth	
	7)		Maxwell equation $\nabla \times H = J + \partial$ Electric flux density	b)	<i>t</i> , <i>J</i> is magnetic flux density	

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Electrodynamics (MSC40202)

Day & Time: Instru

Seat

No.

Q.1

- c) Surface current density
- d) No physical quantity

SLR-FA-12

Set Ρ

		8)	Law which governs the interaction of the electromagnetic field with charge matter	
			a) Gauss law b) Faradays law c) Amperes law d) Lorentz force law	
		9)	Magnetic vector potential due to magnetic dipole is proportional	
			to a) r b) $1/r$ c) $1/r^2$ d) $1/r^3$	
		10)	Electric Potential (Φ) of a quadrupole varies with distance 'r' on its axis as	
			axis as a) $\Phi: r^{-1}$ b) $\Phi: r^{-2}$ c) $\Phi: r^{-3}$ d) $\Phi: r^{3/2}$	
	B)			06
		1) 2) 3) 4) 5) 6)	The charge density of electrostatic field is given by In dipole, the gauss theorem value will be The Ampere law is based on Theorem The electric field over the gaussian surface remains continuous and uniform at every point. In Biot-Savart's law, the magnetic intensity is product of the current. The direction of a propagation of electromagnetic wave is \overline{E} . \overline{B} .	
Q.2			0	16
	a) b)		ain Maxwell's displacement current? e a note on Skin effect and skin depth?	
	c) d)	•	ain the concept of Thomson cross section? e the boundary condition for an electrostatic field \overline{E} .	
Q.3	Ans a)		the following. uss the "Reflection and refraction" of electromagnetic waves at	10
		oblic	lue incidence.	
	b)	Elab	orate the concept of displacement current.	06
Q.4	Ans a)	Expl	5	10
	b)	spac Obta field	ained the expression for the resistance for uniform field &non-uniform	06
Q.5			he following.	^
	a) b)		ve an expression for energy stored in electric and magnetic field. 10 ain the concept of Radiation damping. 06	

Q.6	Ans a) b)	swer the following. Derive the general expression for electromagnetic energy. Discuss Electromagnetic plane waves in stationary medium?	10 06
Q.7	Ans a) b)	swer the following. Explain the concept of radiation from a half wave antenna. What is Gauss law? Explain differential form of its.	10 06

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2023 **PHYSICS (ENERGY STUDIES)** Statistical Physics (MSC40206) Day & Date: Wednesday, 20-12-2023 Max. Marks: 80 Time: 11:00 AM To 02:00 PM **Instructions:** 1) Question No.1 and 2 are compulsory. 2) Attempt any three questions from Q. No. 3 to Q. No. 7. 3) Figure to right indicate full marks. Choose the correct alternatives from the options. Q.1 A) Which law of thermodynamics is the law of conservation of energy? 1) a) First b) Second c) Zero d) Third 2) The phase space is _____ dimensional space. a) 3N b) 6N d) c) N 2N The statistics followed by half spin particles is _____. 3) a) Maxwell-Boltzmann Statistics

b) Fermi-Dirac Statistics

- c) Bose-Einstein Statistics
- d) None of the above

Maxwell-Boltzmann statistics cannot be applied to _____. 4)

- a) Atoms b) Molecules
- c) Photons d) Lattice

The equation of state for an ideal gas is represented as 5)

- a) PV = R/Tb) PV = nRT
- d) PV = RTc) P/V = R/T
- 6) The entropy of an ideal gas at absolute zero is
 - a) ∞ b) 0 c) NkB
 - d) Cannot be calculated

For which gas mutual interaction between the molecules is zero. 7)

- a) real Fermi b) d) Bose c) Ideal
- Total heat of the substance is also known as _____. 8)
 - a) Internal energy b) Entropy
 - c) Thermal Capacity d) Enthalpy

Pressure at the critical point is 9)

a) 3b b) 8/27R d) c) 3*b*/27*Rb* 8a/27Rb

Set Ρ

Seat No.

SLR-FA-13

10) In microcanonical ensembles following parameters remain constant.

	••••
TVN b) E	VN

c) EVT d) $EV\mu$

B) Fill in the blanks OR write true/ false.

- 1) The ratio of the universal gas constant and Avogadro's number is called the velocity constant.
- 2) The transition in β -brass is an example of a second-order phase transition.
- 3) Photon, Phonon, etc. obeys the Fermi Dirac distribution function.
- 4) Entropy in thermodynamics is a measure of the disorder of the system.
- 5) The value of the universal gas constant is 8.3143
- 6) A phase space is a six-dimensional space.

Q.2 Answer the following.

a)

16

06

- a) State the types of ensembles and point out the difference between canonical and Grand Canonical Ensemble.
- **b)** Discuss the conditions for phase equilibrium.
- c) Show that during the second order phase transition $\partial^2 G_1 / \partial T^2 \neq \partial^2 G_2 / \partial T^2$.
- d) What is a partition function? Derive it for Canonical Ensemble.
- e) Explain the P-T diagram of the phase transaction.

Q.3 Answer the following.

Q. 0	, ale nel ale le l						
	a)	Show that Gibb's function is continuous during the first-order phase transition, but the first derivative of Gibb's function changes discontinuously.	10				
	b)	What is a triple point? Explain it with the help of a phase diagram.	06				
Q.4	Ans	wer the following.					
	a)	Write a note on Critical Indices	10				
	b)	Write about Liouville's theorem in a classical presentation.	06				
Q.5	Ans	wer the following.					
	a)	Write about Second order phase transition.	08				
	b)	Write a note on microcanonical, canonical and grand canonical ensembles.	80				
Q.6	Ans	wer the following.					
	a)	Show that the average energy of a single particle of ideal fermi gas is 3/5 times the fermi energy of the system.	10				
	b)	Explain the law of corresponding states.	06				
Q.7	Ans	wer the following.					
	a)	Derive the expression for Fermi energy at strongly degenerate ideal	10				
		Fermi gas.	• •				
	b)	Write about black body radiation.	06				

			PHÝŠICS (ENERGY Semiconductor Physic		•
			day, 05-01-2024 I To 02:00 PM		Max. Marks: 80
Instr	uctio	2) Q. (1) and (2) are compulsory.) Attempt any three from Q. No. 3 to) Figure to right indicate full marks.	Q. N	o. 7
Q.1	A)	Cho 1)	ose the correct alternative. In a semiconductor, the energy ga conduction band is about	p betv	10 ween the valence band and
			a) 5 eV c) 15 eV	b) d)	10 eV 1 eV
		2)	Electron-hole pairs are produced b a) Recombination c) Ionization	b) d)	 Thermal energy Doping
		3)	 The drift velocity of the conductor a) Increase with an increase in t b) Decrease with Decrease in te c) Increase with Decrease in the d) Decrease with the increase in 	emper e temp	ature perature
		4)	In Schottky barrier, barrier height d a) Amount of doping material c) Temperature	-	ds on Type of doping material None of the above
		5)	The probability that an electron in a any temperature (> OK) is a) 0 c) 0.5	a met b) d)	al occupies the fermi level, at 1 1.0
		6)	If σ is the conductivity, what is the and the current density J in a cond a) $\sigma = J/E$ c) $\sigma = E/J$	uctinę b)	
		7)	The equilibrium number of EHP in about a) 10 ¹⁰ EHP/cm ³ c) 10 ¹⁰ EHP/m ³	pure b) d)	10 ¹² EHP/cm ³
		8)	The atoms of solid are held togethe a) Van der Waals forces c) Ionic bonds	er by b) d)	 Hydrogen bonds Hydrophobic forces
		9)	What is the role of seed crystal in o a) Nucleation center c) Solvent	crysta b) d)	l growth? Catalyst Solution

M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2023

Seat No.

Set P

		 10) Charge carriers can move in semiconductor via: a) Diffusion mechanism b) Floating mechanism c) Drift mechanism d) Both drift and diffusion mechanism 	
	В)	 Fill in the blanks OR Write true/ false. 1) The mean lifetime of electron-hole pair (EHP) is less than seconds. 2) LED is an example of luminescence. 3) nuclei often redissolve. 4) Nucleation poses large energy barrier. (True/False) 5) Mobility cannot be determined from Haynes-Shockley experiment. (True/False) 6) Debye temperature is associated with the highest allowed mode of vibration. (True/False) 	\$
Q.2	a) b)	ver the following16Write a note on optical absorption.Explain fermi level pinning.Write a short note on group velocity of electrons.Explain in short direct bandgap semiconductors.	3
Q.3	Ans [.] a) b)	ver the followingElaborate in detail about the ohmic contacts.10Explain in short about Nucleation process.06	
Q.4	Ans [.] a) b)	ver the followingExplain the concept of vibrational specific heat and derive its expression.Write in brief about inverse effective mass tensor.Of	
Q.5	Ans ^r a) b)	ver the followingElaborate in detail about the growth of bulk semiconductors by Zone10Melting.Explain in brief about surface and interface states.06	
Q.6	Ans a) b)	ver the followingExplain the concept of steady state carrier generation.10Write in brief about vapour phase epitaxy.06	
Q.7	a)	ver the following Explain in detail about rectifying contacts with the necessary band 10 diagrams.	
	b)	Explain the bonding forces in solids. 06	כ

	M 0 -	(C	
No.			
Seat			

M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Atomic, Molecular Physics (MSC40302)

Day & Date: Sunday, 07-01-2024 Time: 11:00 AM To 02:00 PM

Instructions: 1) Question no. 1 and 2 are compulsory.

- 2) Attempt any three questions from Q. No. 3 to Q. No. 7.
- 3) Figure to right indicate full marks.

Q.1 A) Multiple choice questions.

- 1) In computing the splitting of spectral lines in a weak magnetic field the lande g-factor arises because of _____.
 - a) Pauli Exclusion Principle b) spin-orbit coupling
 - c) larmor precession d) relativistic correction
- 2) Laser cooling of atoms is produced due to _____.
 - a) Absorption of photons by atoms
 - b) scattering of photons by atoms
 - c) Transfer of momentum from photon to atoms
 - d) transfer of energy from photons to atoms.
- First raman shifted line observed at 218 Cm-1 for CCl4 excited by 632.8nm of HE-Ne laser, will correspond to scattered wavelength at (given h=6.6*10⁻³⁴Js C=3*10⁸m)
 - a) 128.5nm b) 621.8nm
 - c) 5000.0nm d) 641.6 nm
- 4) The outermost shell of an atom of an element is 3d3. The spectral symbol for the ground state

a) ⁴ F _{3/2}	b)	⁴ F9/2
c) ⁴ D _{7/2}	d)	⁴ D _{1/2}

5) A negative muon, which has a mass nearly 200 times that of an electron, replaces an electron in a Li atom. The lowest ionization

energy for the muonic LI atom is approximately.

- a) The same as that of He
- b) The same as that of normal LI
- c) The same as that of normal Be
- d) 200 time larger than that of normal LI
- 6) Which of the following molecules does not exibit a rotational spectrum.
 - a) HCI b) CO
 - c) H2 d) HBr
- 7) JJ coupling is the _____ Coupling.
 - a) Weak b) strong
 - c) less weak d) none of these
- 8) One electron in P orbit and a other in a D orbit, in case of II coupling, the atom may be in a _____ state.
 - a) SPD b) PDF
 - c) DFG d) Only D

Max. Marks: 80

Set

06

16

- 9) Which of the following molecule will not show the microwave spectra.
 - a) CH_2CI_2 b) SF_6
 - c) H₂O d) CH₃CI
- 10) The lowest vibrational energy is given by _____.
 - a) $\frac{1}{2}\omega$ b) ω
 - c) $\frac{1}{2}\omega^2$ d) ω^2

B) Fill in the blanks or True false from give parenthesis

- 1) _____ Detector is an IR detector (crystal / Pyroelectric)
- 2) At J=0 i.e ground rotational state, in which the _____ (rotation / no rotation)
- Intensity rule for the Zeeman effect of the atomic systems containing more than one valance electron is _____ of type of coupling (dependent /Independent)
- 4) When L is greater than or equal to S, all integral Value of J between L-S and L+S are allowed.
- 5) Hyperfine structures arises in tungsten due to presence there even isotopes tungsten.
- 6) The spherical top molecule have dipole moment owing to their symmetry.

Q.2 Answer the following.

- a) Give selection rule for LS and JJ coupling
- **b)** State and explain the intensity rule for Zeeman Effect.
- c) Distinguish between normal and anomalous Zeeman Effect.
- d) Find the spectroscopic term for npl,np2,np4,np5.

Q.3 Answer the following.

- a) With the schematic diagram, write the construction and working of stern
 12 gerlach experiment.
- b) The spin orbit coupling constant for the upper state of Na atom which emits
 D lines for weak numbers 16959cm-1 and 1697.4cm-1 is?

Q.4 Answer the following.

- a) What are the assumption made for the deriving an expression for Lande 'g' factor? Obtain the expression for the Lande 'g' factor for LS coupling.
- b) In a hydrogen atom the accidental or coulomb degeneracy for the n=4 state 04 is? {111}.

Q.5 Answer the following.

- a) Write the consequences for bond elasticity for diatomic molecule as a nonrigid rotator.
- b) The number of Zeeman component for 2D3/2 --> 2P3/2 transition in one 04 electron atom will be?{124}

Q.6 Answer the following.

- a) Discuss the techniques and instrumentation of microwave spectrometer and **12** its use in chemical analysis
- **b)** The land's g factor for the ${}^{3}P_{1}$ level of an atom is? {91}.

Q.7 Answer the following.

- a) Draw the vibrational energy levels and some transition between them for a diatomic molecules undergoing anharmonic oscillations
- b) Consider a state in which I=4, s=1/2 the orientation of total angular moment
 04 w.r.t Cos 45 the state with largest possible J, mj is? {55}

				haracterizatio			
			y, 09-01-2024)2:00 PM			Max. Marks:	80
ructio	2) Atte	Nos. 1 and. 2 ar empt any three o ure to right indic	questions from Q	. Nc	o. 3 to Q. No. 7	
A)	Cho 1)		the correct alte error caused b Random error Gross error	y poor calibratior	b)	the instrument is called Systematic error Precision error	10
	2)	Wha a) c)	at is the averag Infinity Unstable	e velocity of the r	b)	ecules of an ideal gas? Constant Zero	
	3)	pres a) b)	sent in a solid s Quantitative Qualitative Quantitative a	ample.	-	ormation about the compounds	
	4)				of th b)	K direction and the velocity is the magnetic field? Y XY Plane	
	5)	In w a) b) c) d)	Absorption is Absorption is Absorption is	the logarithm of t the reciprocal of	rans tran arithi	smittance m of transmittance	
	6)	AST a) b) c) d)	American Soc American Soc	iety for Tensile N iety for Testing a iety for Tool Mea iety for Tensile N	ind I asure	Materials ement	
	7)	The	pressure exert ause its molecu Strike the wal Strike the wal Strike the wal	ed by the gas on	the ociti e y		
	8)	Whi a)	ich mathematica Fourier Trans	form		X-ray crystallography? Laplace Transform	

Seat	
No	

M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES)

Day & Time:

Instr

Q.1

a) Fourier Transform Partial differentiation

c)

d) Geiger method

SLR-FA-18

Set P

	9)) Hall a) c)	voltage is zero when the Extrinsic P type	b)		
	1(repr	representation of Beer La resents absorption, 'b'repro centration, what does 'a' ro Intensity Absorptivity	esents dis	·	
	 B) W 1) 2) 3) 4) 5) 6)) A sys) The) Cera) Zero) In Ha mag	ue/ False. stem will be error free if we degree of freedom of a tria amics are employed to pro error is an indication of in all Effect, the electric field netic field. orbance has no unit.	atomic gas tect the inf strumenta	s is 6. frastructure from heat.	06
Q.2	 a) Standard b) Standard c) W 	tate the tate and /hat are 1	llowing. postulates of kinetic theory derive Beer Lambert law. the different X-ray camera e refractive index of thin fil	s and whe	ere are they used?	16
Q.3	a) De b) Ex	escribe t xplain th	Ilowing. the Laue method for single e application of UV- Visibl tion of band gap of semice	e absorpti	on spectroscopy in the	08 08
Q.4	a) Ex	xplain th	llowing. e functioning of a vacuum spectrometer? Explain its		nd applications.	08 08
Q.5	a) Ex b) De	xplain th escribe t	llowing. e working of a rotary oil pu the technique of measurer inescence spectroscopy.	•	nd gap in solids using	08 08
Q.6	a) Ex b) Us	xplain th sing the	llowing. e Four probe method for o kinetic theory of gases, ob otal kinetic energy, pressu	otain an ex	pression for the relation	08 08
Q.7			llowing. e methods of sample prep	oration		08 08

Seat No.				Set P
M.S	c. (S	emester - IV) (New) (CBCS PHYSICS (ENERG Semiconductor Devi	SY S	STUDIES)
		nday, 18-12-2023 To 06:00 PM		Max. Marks: 80
Instructio	2) Attempt five questions.) Question No.1 and 2 are comp) Attempt any three from Q. No.		
Q.1 A)		A CCD involves actions. a) charge storage and transfer b) only charge transfer c) only storage d) charge storage and loss		10
	,	Two valley model of TEDs base a) BCS c) RWH	b)	GaAs is proposed by BBS NWH
	,	LEDs fabricated with GaAs emit a) far ultra violet c) visible		wavelength. ultraviolet infrared
		An overlapping gate structure is performance. a) CCD c) LASER	use b) d)	d for improving LED SCR
	5)	Photodetector optical signal o	b)	detects amplify
	6)	The M - S structure forms a) schottky c) ohmic	b)	rier. read non – ohmic
	7)	$(\alpha_1 + \alpha_2)$ approaches where we were a where a state of the second state of t	nen t b) d)	he SCR devices are at forward 1000 1
	8)	A Triacs is used where the trans a) Power c) electron transfer	b)	of large is involved. voltage transfer charge transfer

		 9) In a CCD operation the thermal relaxation time is than the charge storage time. a) longer b) much longer c) shorter d) much shorter 	
		 10) Light emission is not possible in Si due to its a) direct band gap b) high mobility c) indirect band gap d) doping 	
	B)	 Fill in gaps/State True or False 1) Refreshing circuit is incorporated in CCD memory as it provides 2) Pulsed laser can deliver very power. 3) The M-S structure forms barrier. 4) The CCD devices are static. 5) The forward characteristic of a Shockley diode is useful for switching. 6) PUT requires 2 V if gate is biased at 0.8 V. 	06
Q.2	a) b)	wer the following. Programable UJT. Enhancement type MOSFET. Dynamic effect in CCD. Radiative and non-radiative transitions.	16
Q.3	a)	Describe the operating principle of photodiode based on PN junctions, pin configuration and multilayer hetrojunction with. band diagrams and IV characteristics.	10
	b)	Draw block diagram, doping profile, electric field distribution in p-i-n diode.	06
Q.4	a)	Give an account of DIAC and TRIAC with suitable diagrams and IV characteristics.	10
	b)	Explain di/dt protection.	06
Q.5	a) b)	Describe MS structure with band diagram. Charge trapping in MOSFET.	10 06
Q.6	a)	Describe GaAs Gun Oscillator modes in terms of i) Space charge accumulation ii) Quenched domain mode iii) Delayed domain mode Eventsian suggest flow mechanism in MS innetion	10
_	b)	Explain current flow mechanism in MS junction.	06
Q.7	a)	Describe IV characteristics of solar cell. Derive an expression for quantum efficiency of solar cell.	10
	b)	How performance of CCD is improved.	06

Sea No.	t			Set	Ρ	
	M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Nuclear and Particle Physics (MSC40402)					
			esday, 19-12-2023 To 06:00 PM	, Max. Marks	s: 80	
Instr	ucti	2	Q. Nos. 1 and. 2 are compulsory. Attempt any three questions from Q. No. 3 to Figure to right indicate full marks.	o Q. No. 7		
Q.1	A)	Cho 1)	, , , , , , , , , , , , , , , , , , , ,	MeV .6MeV	10	
		2)	The range of energy eV is called as ea) 1eVb) 0.0c) 1KeVd) 0.1			
		3)	The simplest two nucleon system exist in nationala)n-nb)n-pc)p-pd)dos			
		4)	the height of potential barrier faced by an alphanucleus isa) 31.2MeVb) 31.c) 31.2GeVd) 31.			
		5)	, , , , , , , , , , , , , , , , , , , ,	1 KeV BeV		
		6)	/ /	order of - ¹¹ Sec - ²¹ Sec		
		7)	Unit of cross section isa) Fermib) bac) MeVd) nut	rn cleon per cm3		
		8)	Semi empirical mass formula for the binding contains a surface correction term this term of number A of the nucleus a) $A^{-1/3}$ b) $A^{2/3}$	depends on the mass		
			a) $A^{-1/3}$ b) $A^{2/}$ c) $A^{1/3}$ d) A	0		
		9)	, , , , , , , , , , , , , , , , , , , ,	shape of the nuclei is plate of these	·	
		10)	, , , , ,	rmi gas model of these		

	B)	 Fill in the blanks / True or False. 1) Nuclear binding energy usually expressed in units of 2) The exchange particle which holds the quarks together is called 3) In direct reaction incident particle completely have more than Energy per nucleon 4) Cross sectional area of n-p scattering is 4πa²(T/F) 5) In a deuteron, the force between neutron and proton is short range and repulsive (T/F) 6) Nucleons are bosons (T/F) 	06
Q.2	Ans a) b) c) d)	swer in brief. Discuss shape and size, mass and relative abundances of nucleus. Discuss superconductivity model. Write a note on conservation laws. Write a note on cosmic ray.	16
Q.3	Ans a) b)	swer the following. Derive an expression for scattering cross section of two nucleon system and write a note on scattering length. Discuss properties of nuclear forces.	10 06
Q.4	Ans a) b)	swer the following. Describe liquid drop model of nucleus point out its usefulness and limitations in understanding the nuclear phenomenon. Explain the energy levels of shell model. How this helps to explain the occurrence of magic numbers? Draw the diagram.	10 06
Q.5	Ans a) b)	swer the following Explain the nuclear reaction kinematics Obtain an expression for Q value discuss the general solution of the Q equation. Comment on compound nuclear disintegration.	10 06
Q.6	Ans a) b)	Swer the following Give the Gell-Mann-Nisijima relation and calculate the charge of baryon family using this relation find out strangeness' and hypercharge of the baryon octet plot the schematic diagram and table. Discuss quark hypothesis and quantum chromodynamics.	10 06
Q.7	Ans a) b)	swer the following What should be the minimum KE of the electrons to probe the size of ₂₀ Ca ⁴⁰ nucleus. An ₈ O ¹⁶ nucleus is spherical and has charge radius R and volume according to empirical observation of the charge radii, the volume of the ₅₄ Xe ¹²⁸ nucleus assume to be spherical what is the ratio of volume of Xe to the	10 06

volume of Oxygen.

Set

Seat No.

M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (ENERGY STUDIES) Physics of Nano Materials (MSC40403)

Day & Date: Wednesday, 20-12-2023 Time: 03:00 PM To 06:00 PM

Instructions: 1) Question no. 1 and 2 are compulsory.

2) Attempt any three questions from Q. No. 3 to Q. No. 7.3) Figure to right indicate full marks.

Q.1 A) Multiple choice questions.

- 1) The basic principle of AFM is _____
 - a) change in force due to change in distance
 - b) change in current due to change in distance
 - c) change in shape due to change in distance
 - d) change in size due to change in distance
- 2) Nanotubes usually form in bundles. Which is the best description of such a bundle?
 - a) The tubes are aligned, axes parallel, with van der Waals forces operating between adjacent tubes
 - b) The tubes are connected together by covalent C-C bonds
 - c) The tubes are randomly organized, with the axes of the tubes lying in random directions
 - d) The bundles are of discrete sizes, and dipole-dipole forces hold the tubes together
- 3) For emission of the electrons from the metal surface the minimum required energy is _____.
 - a) binding energy of the electron
 - b) work function of the metal
 - c) kinetic energy of the electron
 - d) None of the above
- 4) The extensively used nano particles as catalyst is _____.
 - a) Silver b) Copper
 - c) Gold d) Cerium

5) _____ operate like a single electron transistor.

- a) Quantum wells b) Quantum wires
- c) Quantum dots d) Quantum rings
- 6) The magnified image of the specimen in SEM is obtained
 - a) CRT b) Phosphorescent screen
 - c) Anode d) Scanning generator
- 7) _____ are used in LEDs.
 - a) Quantum wells
 - c) Quantum rings d) Quantum dots
- 8) The electron microscope which is used to study the internal structure of the plant and animal cells is

b)

- a) SÉM
- c) Light microscope
- b) TEM
- d) Compound microscope

Quantum wires

Max. Marks: 80

06

16

9)	Which among the following helps in obtaining a three-dimensional
	picture of the specimen?

a) TEM

- SEM b)
- c) Compound Microscope d) Simple Microscope
- 10) is a requirement for the fluorescence process.
 - a) Absorption Radiation b)
 - c) Transmission d) All of the above

Fill in the blanks / State True or False. B)

- The surface area to volume ratio of a sphere with radius 30 nm is 1)
- In SEM the morphology of the sample is achieved with the help of 2)
- is used for measuring the surface area of the nanoparticles. 3)
- The ball milling technique is a bottom up method. 4)
- In AFM, the sample is mounted on a piezoelectric tube. 5)
- The electron mobility in semiconductors can be greatly decreased by 6) the formation of polarons.

Q.2 Answer the following.

- a) BN Nanotubes
- b) Dielectric quantum confinement
- c) Electrodeposition
- d) Metallic SET

Q.3 Answer the following.

Answer the following.					
b)	Why is spatial resolution of STM better than AFM?	06			
a)	Describe the chemical vapour deposition technique for the preparation of nanomaterials.	10			

a) Describe principle and operation of STM 10 b) Give an account of field-enhanced thermionic emission and field-assisted 06 thermionic emission.

Q.5 Answer the following.

Q.4

a)	Describe the effect of increasing temperature on the conductivity of an	10
	intrinsic semiconductor.	
b)	Explain the basic difference between a PVD and CVD process.	06

Q.6 Answer the following.

- a) Describe the density of states at low-dimensional nanostructures. 10 06
- b) Deduce the hopping conduction mechanism in semiconductors.

Answer the following. Q.7

- a) Describe the basic working principle of an AFM and explain the charge 10 transfer in terms of LDOS. 06
- b) Explain in brief the basic process of VLS technique.

Seat	t			Set	Ρ					
No.	M.S	່ c. (S	emester - IV) (New) (CBCS) Examination: (Oct/Nov-2023						
	PHYSICS (ENERGY STUDIES)									
	Energy Conversion Devices (MSC40406)									
			ursday, 21-12-2023 I To 06:00 PM	Max. Mark	s: 80					
 Instructions: 1) Q. Nos. 1 and 2 are compulsory. 2) Attempt any Three questions from Q.No.3 to Q.No.7. 3) Figures to the right indicate full marks. 										
 Q.1 A) Choose the correct alternatives from the options. 1) material is used as window layer in the solar cell. 					10					
		1)	a) CdSe b) CdTe c) ZnO d) CuInSe2	50n.						
		2)	Solid oxide fuel cells operate at high temperature as a) 250 b) 500 c) 1000 d) 2000	high as°C.						
		3)	Which of these gases or liquids are not used as sour in fuel cells? a) C ₂ H ₆ b) C ₂ H ₂	ce of hydrogen						
			c) C_6H_6 d) C_2H_5OH							
		 Alkali fuel cell operate on compressed and gases a) Hydrogen, oxygen b) Helium, Neon c) Nitrogen, Argon d) None of these 		י						
		5)	Organic solar cells are realized using materiaa) Oligomersb) Polymersc) Both a and bd) None of thes							
		6)	A solar cell is aa) P-type semiconductorb) N-type semiconductorc) Intrinsic semiconductord) P-N Junction							
 7) material is used as window layer in the solar cell. a) CdSe b) CdTe c) ZnO d) CulnSe₂ 		cell.								
		8)	The band gap of the CdS material isa) 3.2 eVb) 1.12 eVc) 0.66 eVd) 2.45 eV							
		9)	The amount of photo generated current increases slincrease ina) Temperatureb) Photonsc) Diode currentd) Shunt current							
		10)	The Fill Factor of the solar cell is FF= a) Vmlm. Voclsc b) Vmlm /Voclsc							

a) Vmlm. Voclscc) VmVoc/ Im lsc b) Vmlm /Voclscd) Voc lsc/Vmlm SLR-FA-22

06

16

Choose the correct alternative: B)

- CdS/Cu₂S based solar cells are a fourth-generation solar cell. 1)
 - False a) True b)
- Shockley queasier limit is defined for Quantum Efficiency. 2)
 - a) True b) False
- Fill factor is ratio of FF = $\frac{Vm \times 1m}{Vm \times 1m}$ 3) True a) b)
 - False is one of the most preferable electrolytes for liquid solar cell.
- 4) Polymer electrolyte membrane fuel cell operate in the temperature 5) range °C.
- The standard emf of the hydrogen-oxygen fuel cell is . 6)

Q.2 Answer the following.

- State the solar cell parameters. a)
- Define diffusion length and carrier life time. b)
- Write in sort about thermoelectric effect. C)
- Write in brief about photovoltaic effect. d)

Answer the following. Q.3

- Give an account of Stabler- Wronski effect in amorphous Si solar cell. 10 a)
- What is the short-circuit current delivered by a 10 cm by 10 cm photocell 06 b) (with100% guantum efficiency) illuminated by monochromatic light of 400 nm wavelength with a power density of 1000 W/m^2 .

Q.4 Answer the following. Describe principle of operation of Solid Oxide Fuel Cells. 10 a) Elaborate the mechanism of metal oxide fuel cell. 06 b) Q.5 Answer the following. Explain the principle and working of Cu₂S solar cell. 10 a) Derive Kelvin's thermodynamic relations. 06 b) Answer the following. Q.6 Write in detail about proton exchange membrane fuel cell. 10 a) Explain in detail about analysis of thermoelectric generators. 06 b)

Q.7 Answer the following.

- Explain the construction and working of Metal oxide fuel cell. 10 a) 06
- Elaborate the construction of energy band diagram of heterojunctions. b)